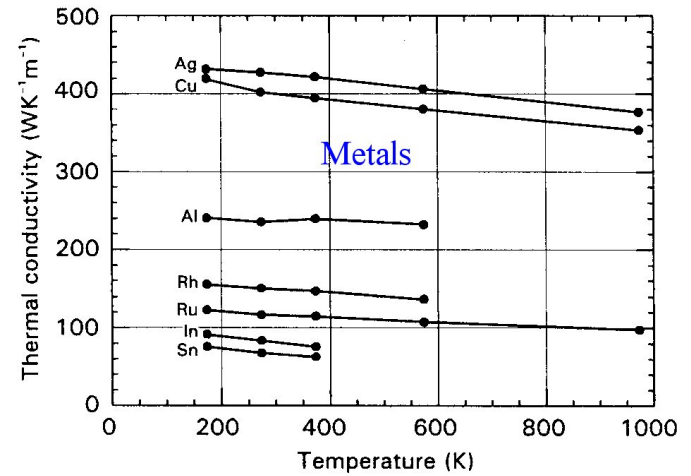


THERMAL CONDUCTIVITY

Lecture 12

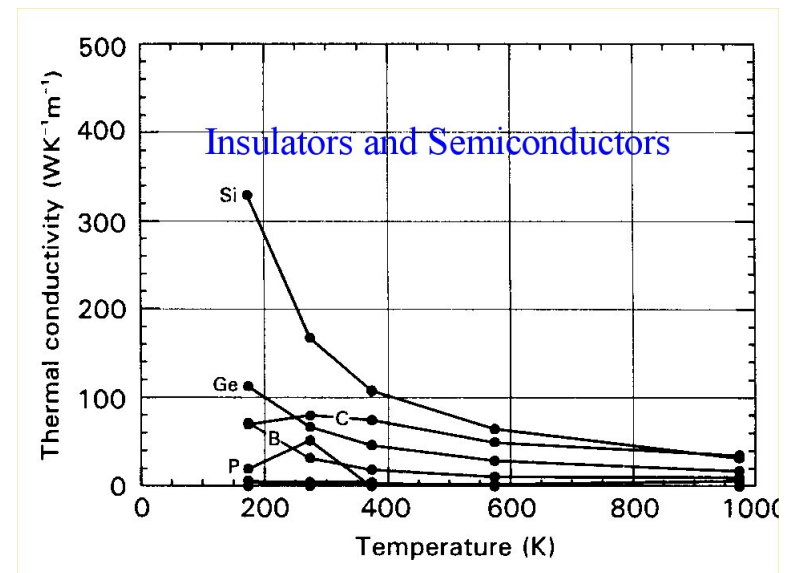
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Thermal Conductivity

Previous Lecture

- Specific heats always tend to classical limit at high T .
- C_V decreases with decreasing T .
- Einstein model decreases too rapidly at low T
- Debye model gives correct T^3 dependence at low T .
- Debye temperature Θ_D as
 - correction factor to get right number of degrees of freedom;
 - fitting parameter.



- Different behaviours of metals compared with insulators and semi-conductors;
- Very large range of values: for elements at room T
 - diamond: up to $2600 \text{ W K}^{-1}\text{m}^{-1}$
 - copper: $400 \text{ W K}^{-1}\text{m}^{-1}$
 - sulphur: $0.3 \text{ W K}^{-1}\text{m}^{-1}$

In the following sections we look at thermal conduction by lattice vibrations.

4.8.1 Phonons as particles

If mode k is in its n_k th excited state, as the energy levels are equally spaced, we can regard this as a state with n_k identical excitations in mode k , each with energy $\hbar\omega_k$. We say there are n_k phonons in mode k – exact analogy with photons. The phonon has energy $\hbar\omega_k$ and momentum $\hbar k$. We can think of the phonon as a particle (*quasiparticle*).

4.8.2 Phonon momentum

The momentum of phonons is rather different to normal momentum. Conservation of momentum is a fundamental property of most systems: it is a result of the fact that the Hamiltonian of a free particle is invariant under translation (p commutes with \mathcal{H}). In a crystal, the Hamiltonian is only invariant under translation through a lattice vector R . As a result, momentum in the crystal is only conserved to within an additive constant $\hbar G$, where G is a reciprocal lattice vector. $\hbar k$ is not a true momentum of the whole crystal – except at $k = 0$ when it corresponds to uniform motion of the whole crystal. $\hbar k$ is called *quasimomentum*.

4.8.3 Phonon interactions

In the harmonic approximation we ignored terms in the Hamiltonian like

$$\sum_{nn'n''} u_n u_{n'} u_{n''} D_{nn'n''},$$

and got normal modes which did not interact. When we look for wave-like solutions, we have terms of the form

$$\sum_{kk'k''} \sum_n A_{kk'k''} \exp(i(\mathbf{k} + \mathbf{k}' + \mathbf{k}'') \cdot \mathbf{R}_n),$$

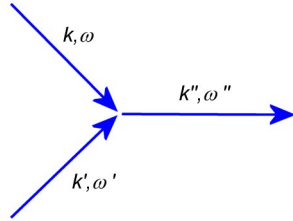
and, as in our discussion of diffraction, the sum will be zero because of phase cancellation unless

$$(\mathbf{k} + \mathbf{k}' + \mathbf{k}'') \cdot \mathbf{R}_n = 2m\pi$$

where m is an integer. But if G is a reciprocal lattice vector, $G \cdot \mathbf{R}_n$ is a multiple of 2π , so all we can say is that

$$\mathbf{k} + \mathbf{k}' + \mathbf{k}'' + \mathbf{G} = 0.$$

As a result of the anharmonic terms, we have phonon-phonon interactions. Physical explanation: a phonon alters the local atomic spacing, so that another phonon sees a difference in the crystal structure and is scattered by it.



From kinetic theory of gases

$$\kappa = \frac{1}{3} n v c_V \Lambda.$$

Note that $n c_V$ is the specific heat *per volume* – contrast the specific heat *per mole* calculated earlier. Unless the phonons interact with something (are scattered) the thermal conductivity will be infinite.

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4.8.4 Heat Transport

Treat phonons as a classical gas of particles, transporting energy $\hbar\omega$ at velocity v , the group velocity of the waves. Hot regions have a higher density of phonons than cool regions. Heat flux (energy/area/time)

Q:

$$Q = -\kappa \nabla T,$$

and κ depends on

- number of particles/volume carrying energy n
- specific heat per carrier c_V
- carrier velocity v
- how far carrier travels before being scattered (mean free path Λ)

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4.8.5 Boundary scattering

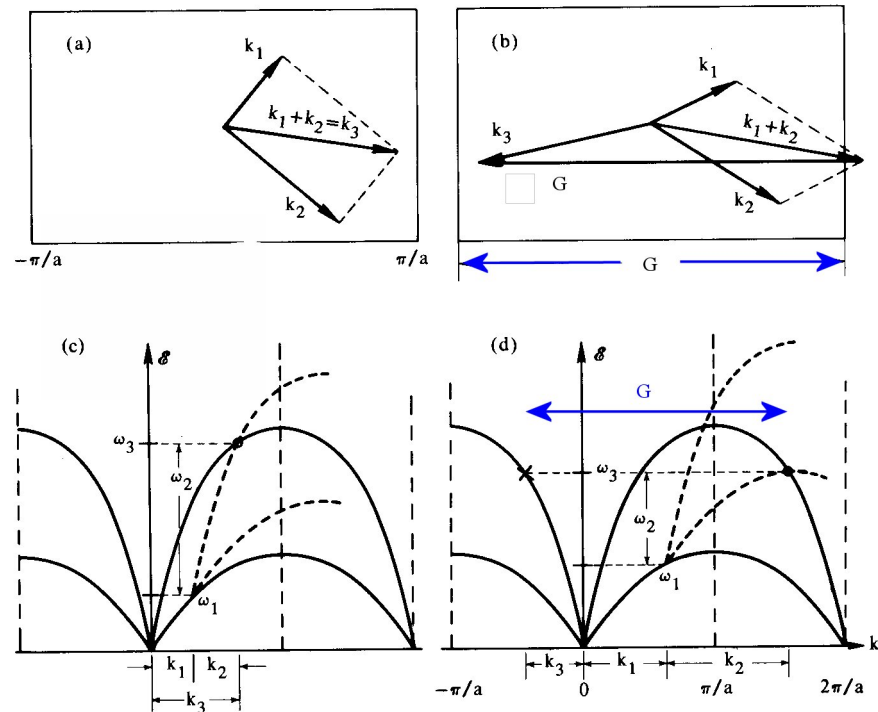
Clearly Λ is limited by the size of the specimen. Generally, the specimen is polycrystalline – Λ is limited by the crystallite size.

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4.8.6 Point defect scattering

Any irregularity in the crystal will scatter a wave. An impurity, or even a different isotope, creates an irregularity. The defect size is about that of an atom. But at low temperatures only low-energy, long-wavelength phonons are excited. Scatterer size $\ll \lambda$ is the condition for Rayleigh scattering $\rightarrow \Lambda \propto \lambda^4$. Dominant phonons at temperature T have $k \propto T$, $\lambda \propto T^{-1}$, and at low T the number of phonons $\propto T^3$ suggesting $\kappa \propto T^3 \times T^{-4} = T^{-1}$. More exact treatment

$$\kappa \propto T^{-\frac{3}{2}}.$$



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4.8.7 Phonon-phonon scattering

At first glance, expect phonon scattering to preserve thermal current, as energy and momentum are both conserved:

$$\begin{aligned} \mathbf{k}_1 + \mathbf{k}_2 &= \mathbf{k}_3 \\ \omega_1 + \omega_2 &= \omega_3 \end{aligned}$$

so even if phonons interact, they continue to carry the energy in the same direction. But remember that the dispersion relation is periodic – this makes a difference.

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If the two initial wavevectors add to a new wavevector which is outside the Brillouin zone, they give a new wave with a group velocity in the opposite direction. Usually, subtract G , a reciprocal lattice vector, to get back into the Brillouin zone:

$$\mathbf{k}_1 + \mathbf{k}_2 - \mathbf{G} = \mathbf{k}_3.$$

Such a process is called an *Umklapp* process (German: flip-over) or *U-process*. Processes in which $G = 0$ are called *N-processes*. Note that for a U-process at least one of the phonons must have $|\mathbf{k}| > \pi/(2a)$ – so very rare at low T . At low T , assume number of phonons with large enough $|\mathbf{k}|$ is $\propto \exp(-\theta/T)$, where θ is a temperature comparable with the Debye temperature. At high T , most of the phonons will have large enough $|\mathbf{k}|$ to give U-processes, and number of phonons $\propto T$.

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4.8.8 Combined processes

Assume all the scattering processes are independent. Each process acts independently to reduce the conductivity. Analogous to resistances in series, so

$$\text{total resistance} = \sum_{\text{processes } i} \text{resistance}_i$$

or

$$\kappa = \frac{1}{\sum_i \frac{1}{\kappa_i}}$$

Look at temperature dependence of terms in

$$\kappa = \frac{1}{3} n v c_V \Lambda;$$

note that v has negligible T dependence.

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High T : can always have enough phonons for U-processes to dominate,

- $n c_V$ independent of T (classical limit)
- $\Lambda \propto T^{-1}$
- $\kappa \propto T^{-1}$

Very low T : U-processes are frozen out, and only have very long- λ phonons so defect scattering small. Boundary scattering dominates:

- $n c_V \propto T^3$
- Λ independent of T (geometry)
- $\kappa \propto T^3$

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Low-intermediate T , isotopically pure U-processes dominate:

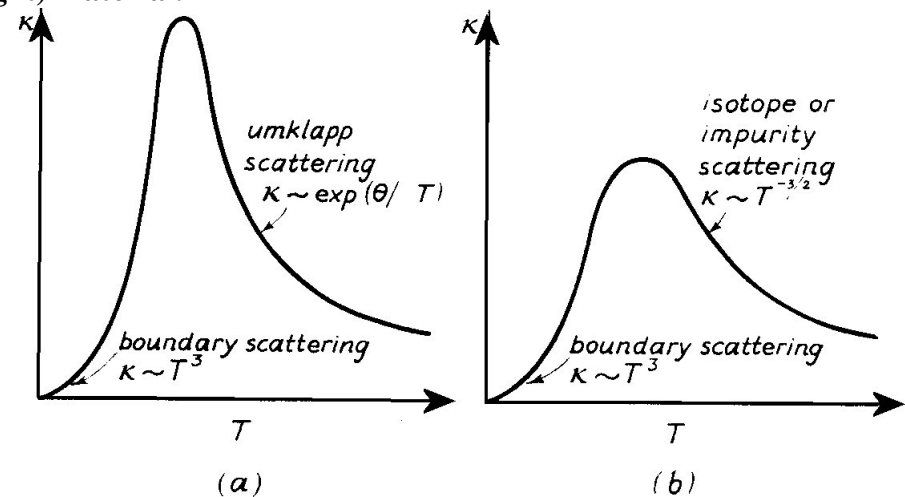
- $n c_V$ only weakly dependent on T compared with
- $\Lambda \propto \exp(\theta/T)$
- $\kappa \propto \exp(\theta/T)$

Low T , impure defect scattering dominates:

- $n c_V \propto T^3$
- $\Lambda \propto T^{-9/2}$
- $\kappa \propto T^{-3/2}$

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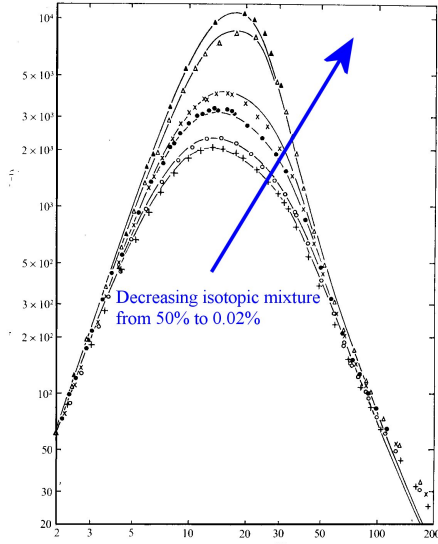
Schematic variation of κ with T for isotopically pure (left) or impure (right) material.



Note steeper rise to higher peak value for pure material.

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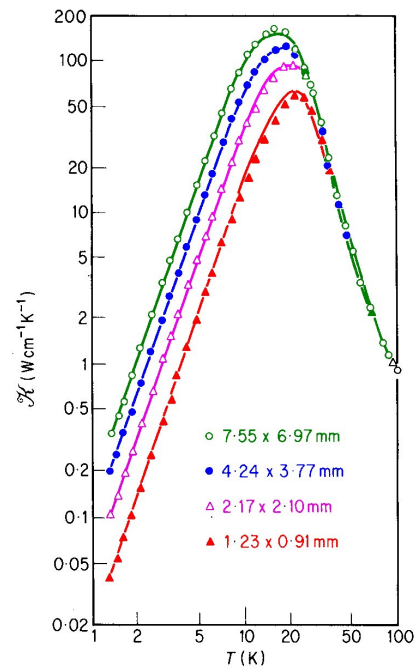
Thermal conductivity of LiF as function of temperature for varying content of ^6Li isotope.



Defect content can be increased by irradiation (e.g. neutron damage in nuclear reactor).

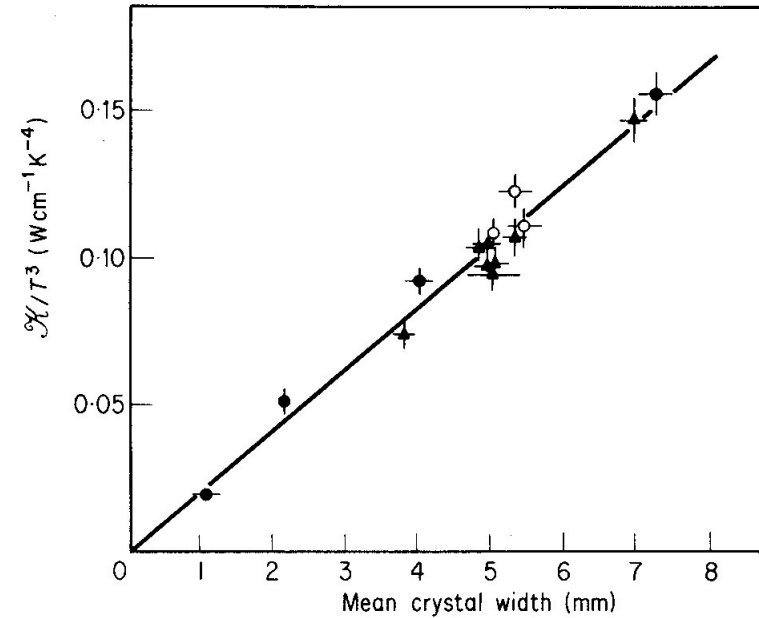
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Thermal conductivity of LiF as function of specimen size at low temperature, showing effect of boundary scattering.



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Thermal conductivity of LiF plotted as κ/T^3 as function of temperature for low temperature.



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Summary

- Phonon scattering limits thermal conductivity
- scattering processes
 - phonon-phonon
 - phonon-defect
 - phonon-grain boundary

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